

MBRF2035CT - MBRF20150CT

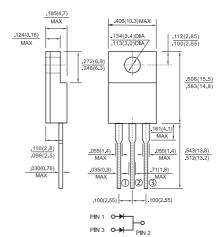
Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications Guardring for overvoltage protection High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- Polarity: As marked

- Mounting position: Any
 Mounting torque: 5 in. lbs. max
 Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	2035 CT	2045 CT	MBRF 2050 CT	MBRF 2060 CT		MBRF 20100 CT		Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current at T _C =135°C	_	20							
Total device	$I_{(AV)}$								Α
Per Leg	10								
Peak Repetitive Forward Current Per leg (Rated V _R , Square Wave, 20KHz) at Tc=135°C	I _{FRM}	20							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150							Α
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0 0.5							Α
Maximum Instantaneous Forward Voltage at (Note 2) I _F =10A, Tc=25°C I _F =10A, Tc=125°C I _F =20A, Tc=25°C I _F =20A, Tc=125°C	V _F	0.	- 57 .84 72	0. 0. 0.	95	0. 0.	85 75 95 85	0.95 0.85 1.05 0.95	٧
Maximum Instantaneous Reverse Current @ Tc=25 °C	0.1			0.1					_
at Rated DC Blocking Voltage @ Tc=125 °C	I_R	15		1	0	5.0			mA
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000						V/uS	
Typical Junction Capacitance	Cj	400 310						pF	
RMS Isolation Voltage (MBRF Type Only) from Terminals to Heatsink with t=1.0 Second, RH $\leq\!30\%$	V _{ISO}		4500 (Note 4) 3500 (Note 5) 1500 (Note 6)						
Typical Thermal Resistance Per Leg (Note 3)	R ₀ JC		1.5 3.5					°C/W	
Operating Junction Temperature Range	TJ	-65 to +150							°C
Storage Temperature Range	Tstg	-65 to +175							°C

- Notes: 1, 2,0us Pulse Width, f=1,0 KHz
 - 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
 - 3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate
 - 4. Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset.
 - 5. Clip Mounting (on case), where leads do overlap heatsink.
 - 6. Screw Mounting with 4-40 screw, where washer diameter is ≦4.9 mm (0.19")

RATINGS AND CHARACTERISTIC CURVES (MBRF2035CT THRU MBRF20150CT)

